## NSN 5961-00-629-1455

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-629-1455 **Inclosure Material:** Glass and metal **Overall Length:** 0.185 inches **Overall Diameter:** 0.235 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 reverse voltage, peak **Current Rating Per Characteristic:** 1.00 amperes source cutoff current preset **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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